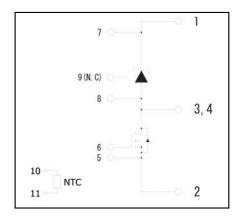
Application

- · Converter
- · Photovoltaics, wind power generation.
- · Induction heating equipment.

Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

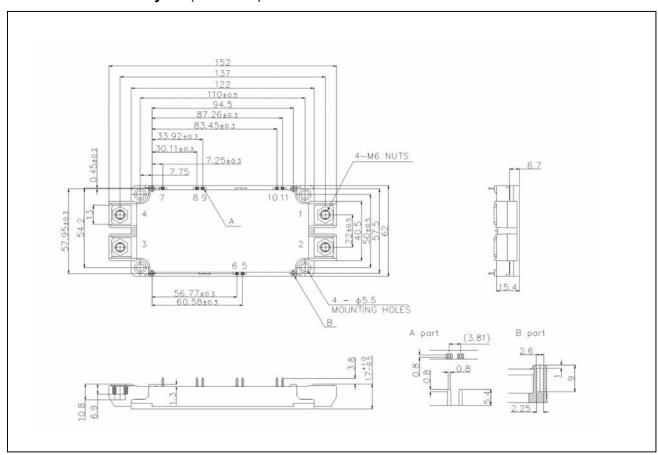
●Circuit diagram



Construction

This product is a chopper module consisting of SiC-DMOSFET and SiC-SBD from ROHM.

● Dimensions & Pin layout (Unit : mm)

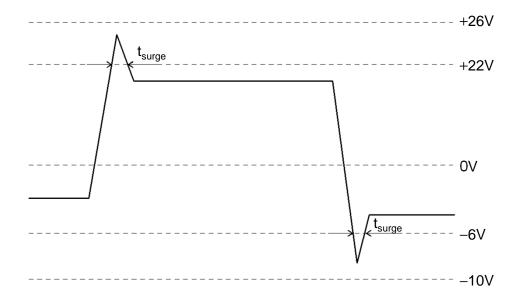


●Absolute maximum ratings (T_j = 25°C)

Parameter	Symbol	Conditions	Limit	Unit		
Drain-source voltage	V_{DSS}	G-S short	1200			
Repetitive reverse voltage	V_{DSS}	Clamp diode	1200			
Gate-source voltage(+)	V_{GSS}	D-S short	22	V		
Gate-source voltage(-)	V GSS	D-3 short	-6			
G - S Voltage (t _{surge} <300nsec)	V_{GSS_surge}	D-S short	-10 to 26			
Drain current *1	I_D	DC (T _c =60°C)	204			
	I _{DRM}	Pulse (T _c =60°C) 1ms *2	360			
	I _{DRM}	Pulse (T _c =60°C) 10us *2 *3	540			
Source current *1	Is	DC (T _c =60°C) V _{GS} =18V	204			
	I _{SRM}	Pulse (Tc=60°C) 1ms V _{GS} =18V * ²	360	Α		
	I _{SRM}	Pulse (Tc=60°C) 10us V _{GS} =18V *2 *3	540			
Forward current (clamp diode) *1	I _F	DC (T _c =60°C)	204			
	I _{FRM}	Pulse (Tc=60°C) 1ms *2	360			
	I _{FRM}	Pulse (Tc=60°C) 10us *2 *3	540			
Total power dissipation *3	Ptot	T _c =25°C	1360	W		
Max Junction Temperature	T_{jmax}		175			
Operating junction temperature			-40 to150	°C		
Storage temperature	T _{stg}		-40 to125	1		
Isolation voltage	Visol	Terminals to baseplate, f=60Hz AC 1min.	2500	Vrms		
Mounting torque		Main Terminals : M6 screw	4.5	N·m		
	_	Mounting to heat shink: M5 screw	3.5			

- (*1) Case temperature (T_c) is defined on the surface of base plate just under the chips.
- (*2) Repetition rate should be kept within the range where temperature rise if die should not exceed $T_{j\,max}$.
- (*3) Please use an appropriate external gate resistor not to exceed maximum ratings of Drain Source Voltage.
- (*4) T_i is less than 175°C

Example of acceptable V_{GS} waveform

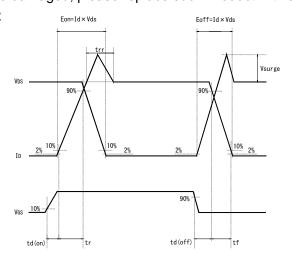


●Electrical characteristics (T_i=25°C)

Symbol	Conditions		Min.	Тур.	Max.	Unit
V _{DS(on)}	I _D =180A, V _{GS} =18V	T _j =25°C	ı	2.2	3.2	V
		T _j =125°C	ı	3.1	-	
		T _j =150°C	ı	3.5	5.0	
I _{DSS}	V _{DS} =1200V, V _{GS} =0V	V _{DS} =1200V, V _{GS} =0V		-	10	μΑ
V_{F}	I _F =180A	T _j =25°C	ı	1.6	2.2	V
		T _j =125°C		2.0	-	
		T _j =150°C	ı	2.2	3.3	
I_{RRM}	Clamp diode	-	-	3.2	mA	
$V_{GS(th)}$	V_{DS} =10V, I_{D} =35.2mA	1.6	-	4	V	
I_{GSS}	V_{GS} =22V, V_{DS} =0V		ı	-	0.5	μА
	V_{GS} = -6V, V_{DS} =0V		-0.5	-	-	
t _{d(on)}	$V_{GS(on)}=18V, V_{GS(off)}=0$	ı	49	-	ns	
t _r	V _{DS} =600V	-	36	-		
t _{rr}	I _D =180A	-	20	-		
t _{d(off)}	$R_{G(on)}=1.0\Omega$, $R_{G(off)}=0.2$	ı	139	-		
t _f	inductive load	ı	32	-		
Ciss	V _{DS} =10V, V _{GS} =0V, 200	ı	20	-	nF	
R_{Gint}	T _j =25°C	-	1.2	-	Ω	
R25			5.0		kΩ	
B50/25			3370		K	
Ls			13.0	-	nΗ	
-	Terminal to heat sink			14.5	-	mm
	Terminal to terminal			15.0	-	mm
-	Terminal to heat sink			12.0	-	mm
	Terminal to terminal			9.0	-	mm
R _{th} (j-c)	DMOSFET (1/2 module) *5		-	-	0.11	K/W
	SBD (1/2 module) *5		-	-	0.14	
R _{th} (c-f)		1 module,		0.035	-	K/VV
	Thermal grease appie	d * ⁶	-			
	I_{DSS} V_{F} I_{RRM} $V_{GS(th)}$ I_{GSS} $t_{d(on)}$ t_{r} t_{f} $Ciss$ R_{Gint} $R25$ $B50/25$ Ls $-$ $R_{th}(j-c)$	$\begin{array}{ c c c } & V_{DS(on)} & I_{D}{=}180\text{A}, V_{GS}{=}18\text{V} \\ \hline & I_{DSS} & V_{DS}{=}1200\text{V}, V_{GS}{=}0\text{V} \\ \hline & V_{F} & I_{F}{=}180\text{A} \\ \hline & I_{RRM} & Clamp diode \\ \hline & V_{GS(th)} & V_{DS}{=}10\text{V}, I_{D}{=}35.2\text{mA} \\ \hline & I_{GSS} & V_{GS}{=}22\text{V}, V_{DS}{=}0\text{V} \\ \hline & V_{GS}{=}-6\text{V}, V_{DS}{=}0\text{V} \\ \hline & t_{r} & V_{DS}{=}600\text{V} \\ \hline & t_{r} & I_{D}{=}180\text{A} \\ \hline & t_{d(off)} & R_{G(on)}{=}1.0\Omega, R_{G(off)}{=}0.2 \\ \hline & t_{f} & \text{inductive load} \\ \hline & Ciss & V_{DS}{=}10\text{V}, V_{GS}{=}0\text{V}, 200 \\ \hline & R_{Gint} & T_{j}{=}25^{\circ}\text{C} \\ \hline & R25 & \\ \hline & B50/25 & \\ \hline & Ls & \\ \hline & & Terminal \text{to heat sink} \\ \hline & Terminal \text{to heat sink} \\ \hline & Terminal \text{to heat sink} \\ \hline & Terminal \text{to terminal} \\ \hline & R_{th}(j{-}c) & DMOSFET (1/2 \text{module}) *^{5} \\ \hline & R_{th}(j{-}c) & Case \text{to heat sink}, \text{per} \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

^(*5) Measurement of T_{c} is to be done at the point just beneath the chip.

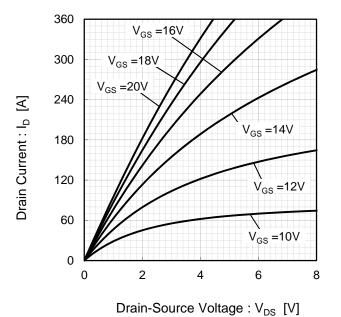
Waveform for switching test

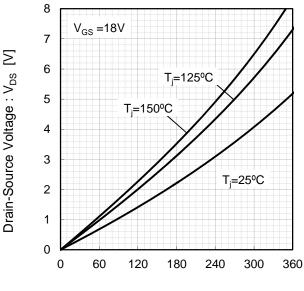


^(*6) Typical value is measured by using thermally conductive grease of λ =0.9W/(m·K).

^(*7) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be damaged, please replace such Product with a new one.

Fig.1 Typical Output Characteristics [T_i =25°C] Fig.2 Drain-Source Voltage vs. Drain Current





Diam-Source voltage . VDS [V]

Drain Current : I_D [A]

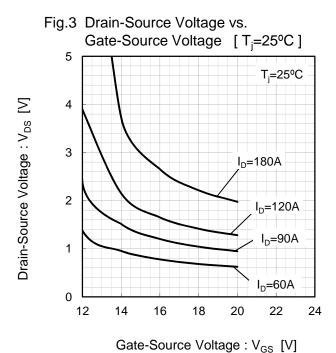
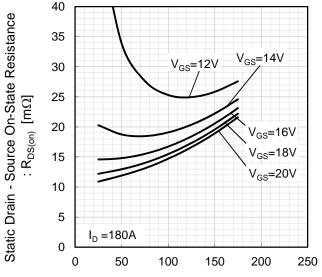


Fig.4 Static Drain - Source On-State Resistance vs. Junction Temperature



Junction Temperature : T_i [°C]

Fig.5 Forward characteristic of Diode

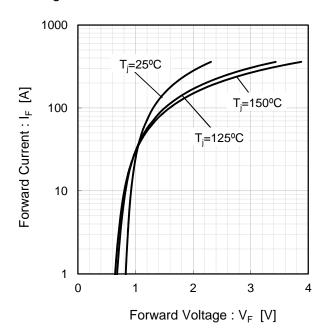


Fig.6 Forward characteristic of Diode

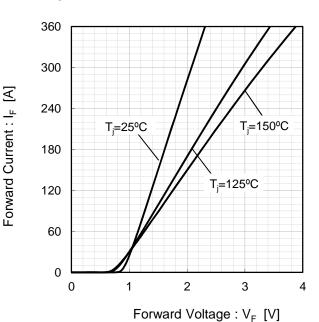


Fig.7 Drain Current vs. Gate-Source Voltage

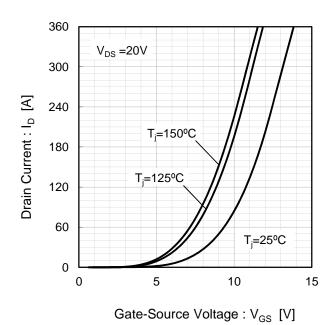


Fig.8 Drain Current vs. Gate-Source Voltage

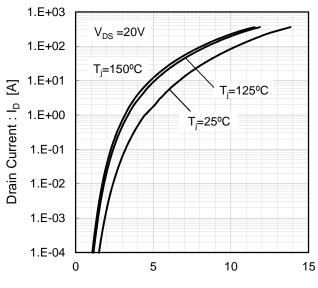


Fig.9 Switching Characteristics [T_i=25°C]

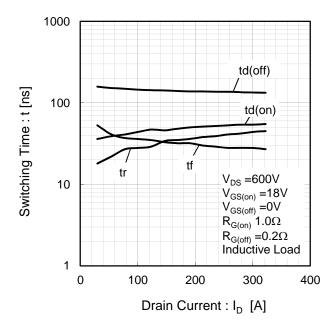


Fig.10 Switching Characteristics [T_i=125°C]

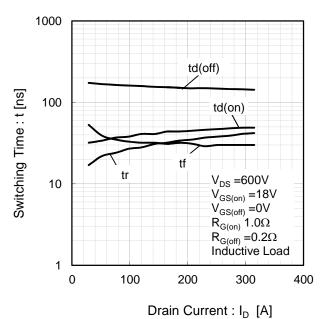


Fig.11 Switching Characteristics [T_i=150°C]

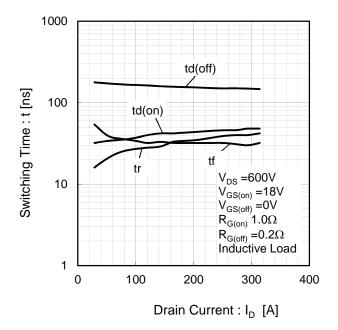
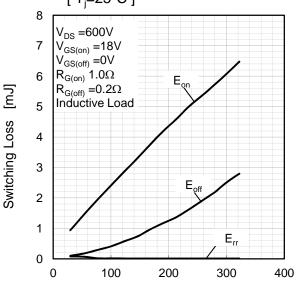


Fig.12 Switching Loss vs. Drain Current [$T_i=25^{\circ}C$]



Drain Current : I_D [A]

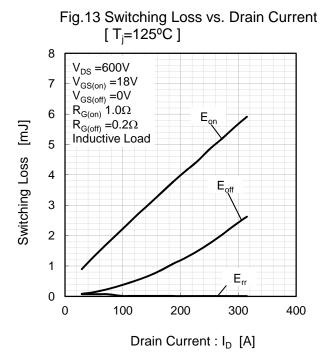
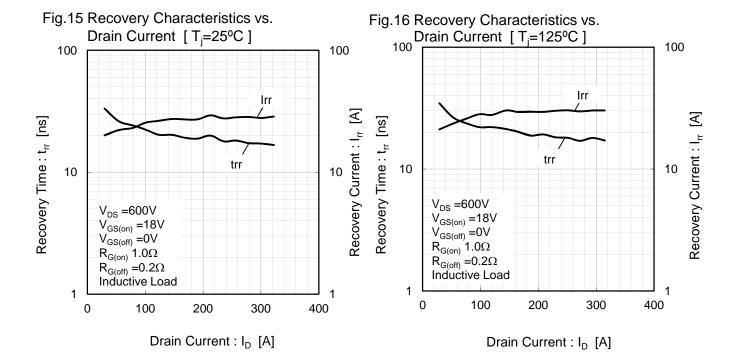
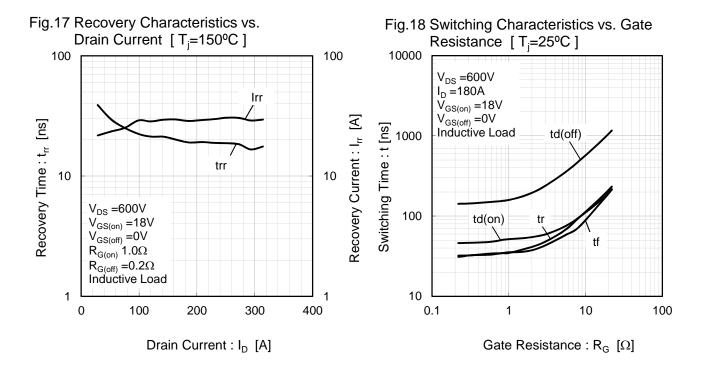
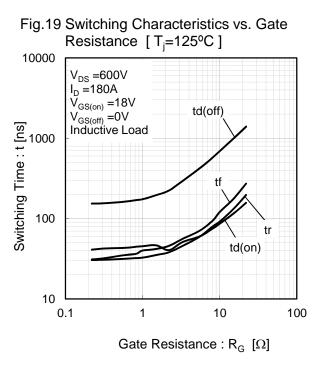
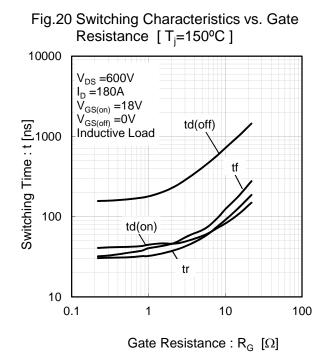


Fig.14 Switching Loss vs. Drain Current $[T_i=150^{\circ}C]$ 8 V_{DS} =600V $V_{GS(on)} = 18V$ 7 $V_{GS(off)} = 0V$ $R_{G(on)} = 1.0\Omega$ 6 $R_{G(off)} = 0.2\Omega$ Switching Loss [mJ] Inductive Load 5 4 3 2 1 E_{rr} 0 0 100 200 300 400 Drain Current: I_D [A]









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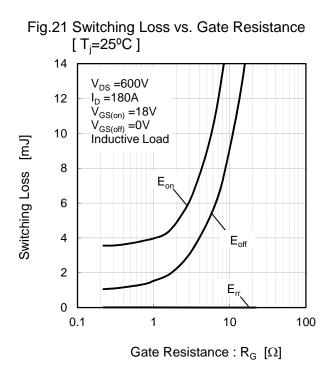


Fig.22 Switching Loss vs. Gate Resistance [T_i=125°C] 14 $V_{DS} = 600V$ $I_{D} = 180A$ 12 $V_{GS(off)} = 18V$ $V_{GS(off)} = 0V$ Inductive Load 10 8 Eor 6 $\mathsf{E}_{\mathsf{off}}$ 4 2 E_{rr} 0 0.1 10 100 Gate Resistance : R_G [Ω]

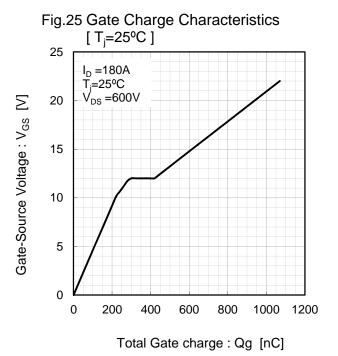
Fig.23 Switching Loss vs. Gate Resistance $[T_i=150^{\circ}C]$ 14 V_{DS} =600V 12 $I_{D} = 180A$

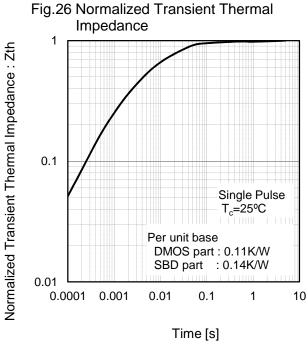
 $V_{GS(on)} = 18V$ $V_{GS(off)} = 0V$ 10 Switching Loss [mJ] Inductive Load 8 6 $\mathsf{E}_{\mathsf{off}}$ 4 2 0 0.1 10 100 Gate Resistance : R_G [Ω]

Voltage 1.E-07 C_{iss} 1.E-08 囯 Capasitance: C $\mathsf{C}_{\mathsf{oss}}$ 1.E-09 1.E-10 T;=25°C C_{rss} $V'_{GS} = 0V$ 200kHz 1.E-11 10 1000 0.01 100 Drain-Source Voltage: V_{DS} [V]

Fig.24 Typical Capacitance vs. Drain-Source

Switching Loss [mJ]





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